

BD436, BD438, BD440, BD442

Plastic Medium Power Silicon PNP Transistor

This series of plastic, medium-power silicon PNP transistors can be used for amplifier and switching applications. Complementary types are BD437 and BD441.

Features

- Pb-Free Package is Available

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	BD436 BD438 BD440 BD442	V_{CEO} 32 45 60 80	Vdc
Collector-Base Voltage	BD436 BD438 BD440 BD442	V_{CBO} 32 45 60 80	Vdc
Emitter-Base Voltage	V_{EBO}	5.0	Vdc
Collector Current	I_C	4.0	Adc
Base Current	I_B	1.0	Adc
Total Device Dissipation @ $T_C = 25^\circ\text{C}$ Derate above 25°C	P_D	36 288	W W/°C
Operating and Storage Junction Temperature Range	T_J, T_{stg}	-55 to +150	°C

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

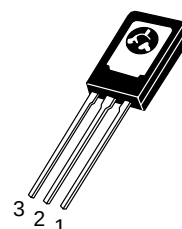
Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Case	θ_{JC}	3.5	°C/W



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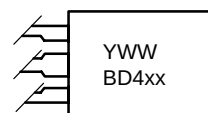
<http://onsemi.com>

4.0 A POWER TRANSISTORS PNP SILICON



TO-225AA
CASE 77
STYLE 1

MARKING DIAGRAM



xx = 36, 38, 40, 42
Y = Year
WW = Work Week

ORDERING INFORMATION

Device	Package	Shipping†
BD436	TO-225AA	500 Units/Box
BD438	TO-225AA	500 Units/Box
BD436TG	TO-225AA (Pb-Free)	500 Units/Box
BD436T	TO-225AA	500 Units/Rail
BD440	TO-225AA	500 Units/Box
BD442	TO-225AA	500 Units/Box

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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ELECTRICAL CHARACTERISTICS ($T_C = 25^\circ\text{C}$ unless otherwise noted)

Characteristic		Symbol	Min	Typ	Max	Unit
Collector–Emitter Breakdown Voltage ($I_C = 100\text{ mA}$, $I_B = 0$)	BD436 BD438 BD440 BD442	$V_{(BR)CEO}$	32 45 60 80	– – – –	– – – –	Vdc
Collector–Base Breakdown Voltage ($I_C = 100\text{ }\mu\text{A}$, $I_B = 0$)	BD436 BD438 BD440 BD442	$V_{(BR)CBO}$	32 45 60 80	– – – –	– – – –	Vdc
Emitter–Base Breakdown Voltage ($I_E = 100\text{ }\mu\text{A}$, $I_C = 0$)		$V_{(BR)EBO}$	5.0	–	–	Vdc
Collector Cutoff Current ($V_{CB} = 32\text{ V}$, $I_E = 0$) ($V_{CB} = 45\text{ V}$, $I_E = 0$) ($V_{CB} = 60\text{ V}$, $I_E = 0$) ($V_{CB} = 80\text{ V}$, $I_E = 0$)	BD436 BD438 BD440 BD442	I_{CBO}	– – – –	– – – –	0.1 0.1 0.1 0.1	mAdc
Emitter Cutoff Current ($V_{EB} = 5.0\text{ V}$)		I_{EBO}	–	–	1.0	mAdc
DC Current Gain ($I_C = 10\text{ mA}$, $V_{CE} = 5.0\text{ V}$)	BD436 BD438 BD440 BD442	h_{FE}	40 30 20 15	– – – –	– – – –	
DC Current Gain ($I_C = 500\text{ mA}$, $V_{CE} = 1.0\text{ V}$)	BD436 BD438 BD440 BD442	h_{FE}	85 85 40 40	– – – –	475 375 475 475	
DC Current Gain ($I_C = 2.0\text{ A}$, $V_{CE} = 1.0\text{ V}$)	BD436 BD438 BD440 BD442	h_{FE}	50 40 25 15	– – – –	– – – –	
Collector Saturation Voltage ($I_C = 2.0\text{ A}$, $I_B = 0.2\text{ A}$) ($I_C = 3.0\text{ A}$, $I_B = 0.3\text{ A}$)	BD436 BD438 BD440 BD442	$V_{CE(sat)}$	– – – –	– – – –	0.5 0.7 0.8 0.8	Vdc
Base–Emitter On Voltage ($I_C = 2.0\text{ A}$, $V_{CE} = 1.0\text{ V}$)	BD436/BD438 BD440/BD442	$V_{BE(ON)}$	– –	– –	1.1 1.5	Vdc
Current–Gain – Bandwidth Product ($V_{CE} = 1.0\text{ V}$, $I_C = 250\text{ mA}$, $f = 1.0\text{ MHz}$)		f_T	3.0	–	–	MHz

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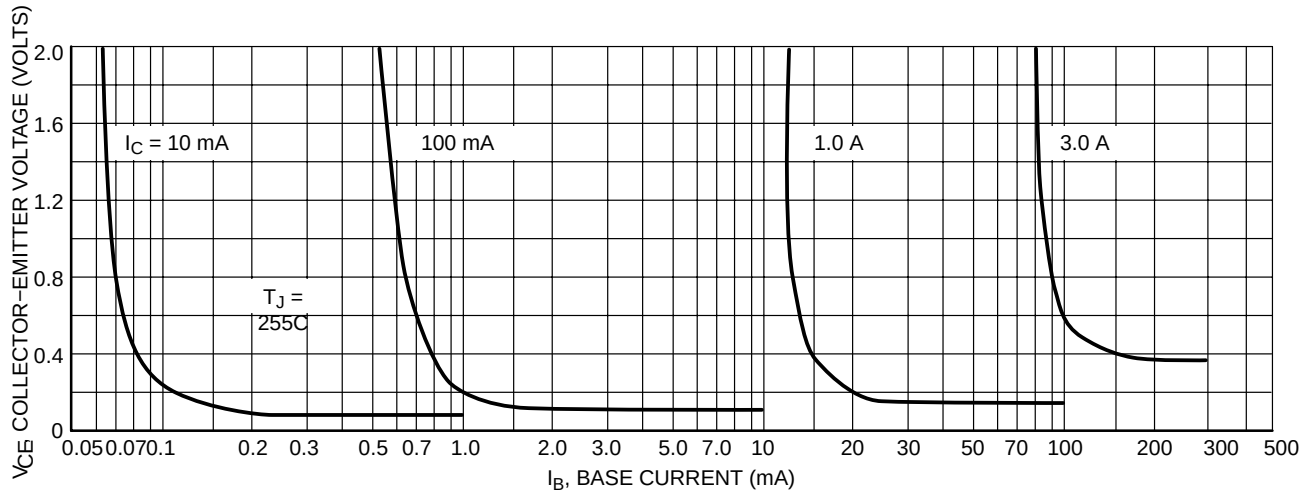


Figure 1. Collector Saturation Region

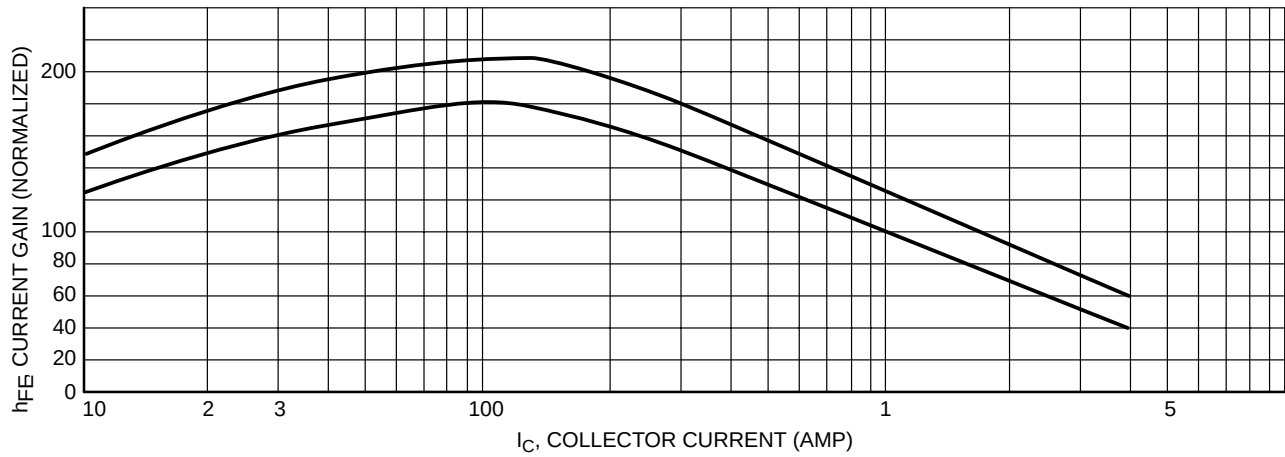


Figure 2. Current Gain

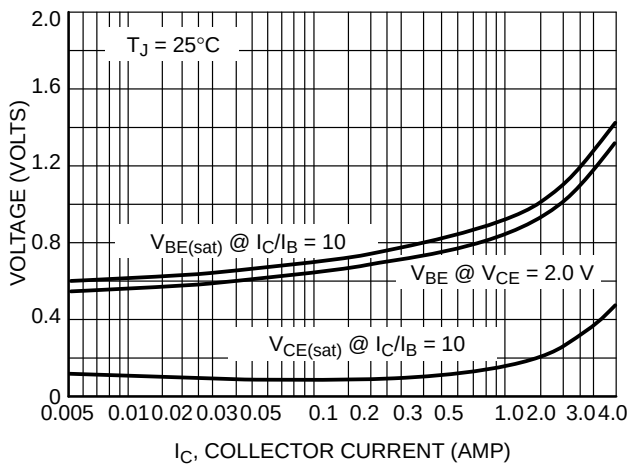


Figure 3. "On" Voltage

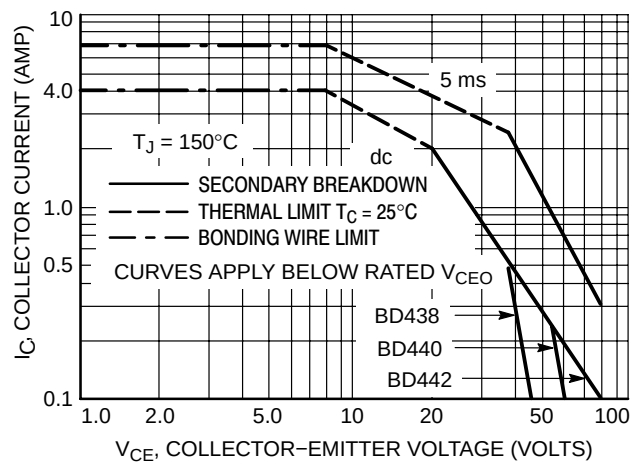
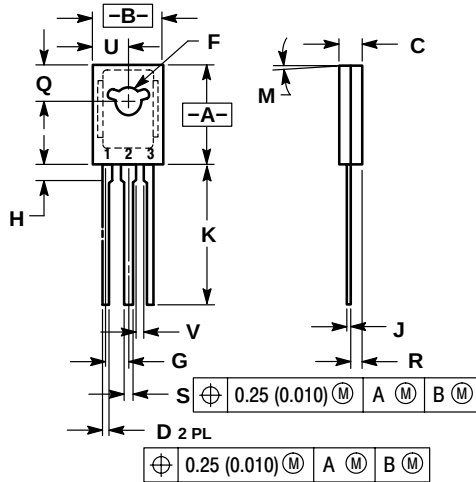


Figure 4. Active Region Safe Operating Area

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PACKAGE DIMENSIONS

TO-225AA
CASE 77-09
ISSUE Z



NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. 077-01 THRU -08 OBSOLETE, NEW STANDARD 077-09.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.425	0.435	10.80	11.04
B	0.295	0.305	7.50	7.74
C	0.095	0.105	2.42	2.66
D	0.020	0.026	0.51	0.66
F	0.115	0.130	2.93	3.30
G	0.094 BSC		2.39 BSC	
H	0.050	0.095	1.27	2.41
J	0.015	0.025	0.39	0.63
K	0.575	0.655	14.61	16.63
M	5° TYP		5° TYP	
Q	0.148	0.158	3.76	4.01
R	0.045	0.065	1.15	1.65
S	0.025	0.035	0.64	0.88
U	0.145	0.155	3.69	3.93
V	0.040		1.02	

STYLE 1:

1. EMITTER
2. COLLECTOR
3. BASE

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